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UserID: JMaldonado

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Date: 06/13/2002

Time: 15:17

	Type	Hits	Search Text	DBs	Time Stamp
1	IS&R	6	((("6077257") or ("6077751") or ("6303520"))).PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT;	2002/06/04 13:39
2	BRS	69	kick adj out adj mechanism	USPAT; US-PGPUB; EPO; JPO; DERWENT;	2002/06/04 13:40
3	BRS	61	(kick adj out adj mechanism) and @ad<=19990503	USPAT; US-PGPUB; EPO; JPO; DERWENT;	2002/06/04 13:40
4	BRS	4	5151766.URPN.	USPAT	2002/06/04 14:29
5	BRS	9	("3888701" "3933527" "4056408" "4115798" "4240844" "4249962" "4278475" "4406709" "4987087").PN.	USPAT	2002/06/04 14:30
6	IS&R	5887	((438/795) or (438/796) or (438/797) or (438/798) or (438/799) or (438/492) or (438/477) or (438/766) or (438/769) or (438/775) or (438/778) or (438/786) or (438/791) or (438/5) or (257/55) or (257/63) or (257/171) or (257/219) or (257/609) or (257/617) or (257/649)).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/05 11:29
7	BRS	5109	((((438/795) or (438/796) or (438/797) or (438/798) or (438/799) or (438/492) or (438/477) or (438/766) or (438/769) or (438/775) or (438/778) or (438/786) or (438/791) or (438/5) or (257/55) or (257/63) or (257/171) or (257/219) or (257/609) or (257/617) or (257/649)).CCLS.) and @ad<=19990503	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/04 15:05
8	BRS	1867	(control controlling controlled controls) same (defect vancancy) same (gas)	USPAT; US-PGPUB; EPO; JPO; DERWENT;	2002/06/04 15:09
9	BRS	168	((control controlling controlled controls) same (defect vancancy) same (gas)) and ((silicon adj oxynitride) (silicon adj nitride))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/05 13:16
10	BRS	8	("4705591" "4755865" "4766477" "4772927" "4968384" "4998150" "5463978" "5683934").PN.	USPAT	2002/06/04 17:13
11	BRS	4	(boron b) and (defect adj enhanced adj diffusion)	USPAT; US-PGPUB; EPO; JPO; DERWENT;	2002/06/05 11:23
12	BRS	4	(boron b arsenic as antimony sb indium in) and (defect adj enhanced adj diffusion)	USPAT; US-PGPUB; EPO; JPO; DERWENT;	2002/06/05 11:26

	Comments	Error Definition	Errors
1			0
2			0
3			0
4			0
5			0
6			0
7			0
8			0
9			0
10			0
11			0
12			0

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	Type	Hits	Search Text	DBs	Time Stamp
13	BRS	4	((boron b arsenic as antimony sb indium in) and (((defect trasient) adj enhanced adj diffusion)	USPAT; US-PGPUB; EPO; JPO; DERWENT;	2002/06/05 11:28
14	BRS	5436	((boron b arsenic as antimony sb indium in) and (((defect trasient) adj enhanced adj diffusion) gettering)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/05 11:29
15	IS&R	6409	((438/795) or (438/796) or (438/797) or (438/798) or (438/799) or (438/492) or (438/477) or (438/766) or (438/769) or (438/775) or (438/778) or (438/786) or (438/791) or (438/5) or (257/55) or (257/63) or (257/171) or (257/219) or (257/609) or (257/617) or (257/649) or (438/143) or (438/476) or (438/472) or (438/473)).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/05 11:30
16	BRS	5557	((438/795) or (438/796) or (438/797) or (438/798) or (438/799) or (438/492) or (438/477) or (438/766) or (438/769) or (438/775) or (438/778) or (438/786) or (438/791) or (438/5) or (257/55) or (257/63) or (257/171) or (257/219) or (257/609) or (257/617) or (257/649) or (438/143) or (438/476) or (438/472) or (438/473)).CCLS.) and @ad<=19990503	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/05 11:31
17	BRS	1208	((438/795) or (438/796) or (438/797) or (438/798) or (438/799) or (438/492) or (438/477) or (438/766) or (438/769) or (438/775) or (438/778) or (438/786) or (438/791) or (438/5) or (257/55) or (257/63) or (257/171) or (257/219) or (257/609) or (257/617) or (257/649) or (438/143) or (438/476) or (438/472) or (438/473)).CCLS.) and @ad<=19990503) and ((silicon adj oxynitride) siono sion (silicon adj nitride) sin)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/05 11:32

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	Comments	Error Definition	Errors
13			0
14			0
15			0
16			0
17			0

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	Type	Hits	Search Text	DBs	Time Stamp
18	BRS	328	((((438/795) or (438/796) or (438/797) or (438/798) or (438/799) or (438/492) or (438/477) or (438/766) or (438/769) or (438/775) or (438/778) or (438/786) or (438/791) or (438/5) or (257/55) or (257/63) or (257/171) or (257/219) or (257/609) or (257/617) or (257/649) or (438/143) or (438/476) or (438/472) or (438/473)).CCLS.) and @ad<=19990503) and ((silicon adj oxynitride) siono sion (silicon adj nitride sin)) and (control same (gas temperature thermal concentration	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/05 11:49
19	BRS	150	((((438/795) or (438/796) or (438/797) or (438/798) or (438/799) or (438/492) or (438/477) or (438/766) or (438/769) or (438/775) or (438/778) or (438/786) or (438/791) or (438/5) or (257/55) or (257/63) or (257/171) or (257/219) or (257/609) or (257/617) or (257/649) or (438/143) or (438/476) or (438/472) or (438/473)).CCLS.) and @ad<=19990503) and ((silicon adj oxynitride) siono sion (silicon adj nitride sin)) and (control same (gas temperature thermal concentration pressure))) and (defect vacancy vacant) and (creation generation generate formation forming	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/05 13:01
20	BRS	986	(generating creating) adj defect	USPAT; US-PGPUB; EPO; JPO; DERWENT;	2002/06/05 13:02
21	BRS	105	((generating creating) adj defect) and (semiconductor with material)	USPAT; US-PGPUB; EPO; JPO; DERWENT;	2002/06/05 13:07
22	BRS	83	((generating creating) adj defect) and (semiconductor with material)) and @ad<=19990503	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/05 13:08
23	BRS	21	((generating creating) adj defect) and (semiconductor with material)) and @ad<=19990503) and (silicon adj (nitride oxynitride))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/05 13:08

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	Comments	Error Definition	Errors
18			0
19			0
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21			0
22			0
23			0

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	Type	Hits	Search Text	DBs	Time Stamp
24	BRS	423	((control controlling controlled controls) same (defect vancancy) same (temperature (partial adj pressure)) and ((silicon adj oxynitride) (silicon adj	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/05 13:20
25	BRS	319	((((control controlling controlled controls) same (defect vancancy) same (temperature (partial adj pressure)) and ((silicon adj oxynitride) (silicon adj nitride)))) and @ad<=19990503	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/05 13:20
26	BRS	273	(((((control controlling controlled controls) same (defect vancancy) same (temperature (partial adj pressure)) and ((silicon adj oxynitride) (silicon adj nitride)))) and @ad<=19990503) and thickness	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/05 13:21
27	BRS	176	((((((control controlling controlled controls) same (defect vancancy) same (temperature (partial adj pressure)) and ((silicon adj oxynitride) (silicon adj nitride)))) and @ad<=19990503) and thickness) and concentration	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/05 13:21
28	BRS	34	((((((((control controlling controlled controls) same (defect vancancy) same (temperature (partial adj pressure)) and ((silicon adj oxynitride) (silicon adj nitride)))) and @ad<=19990503) and thickness) and concentration) and (thermal with stress)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/05 13:22

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	Comments	Error Definition	Errors
24			0
25			0
26			0
27			0
28			0